NSN 5961-01-113-1661

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-113-1661 **Inclosure Material:** Metal **Overall Length:** Between 0.165 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-78 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor and 4.5 gate to source cutoff voltage all transistor **Current Rating Per Characteristic:** 10.00 microamperes gate current all transistor and 10.00 milliamperes forward gate current all transistor **Power Rating Per Characteristic:** 40.0 milliwatts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No